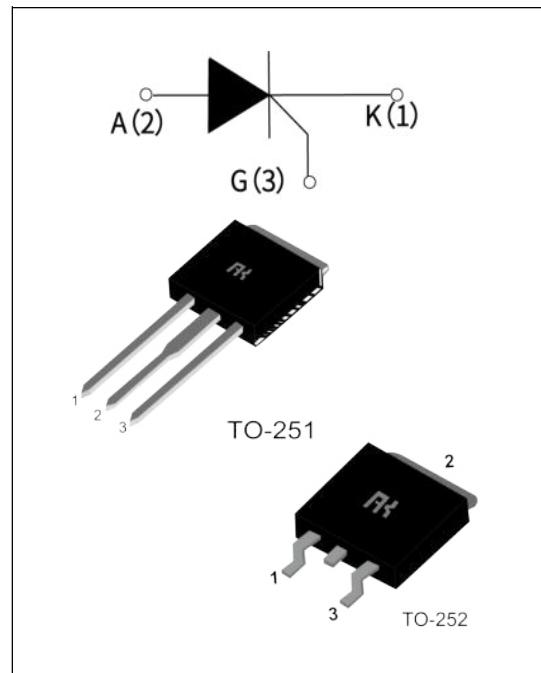


## TN415 Serial 4ASCRs

### GENERAL DESCRIPTION:

Glass passivated,sensitive gate thyristors in a plastic envelope,intended for use in general purpose switching and phase control applications.

These devices are intended to be interfaced directly to microcontrollers,logic integrated circuits and other low power gate trigger circuits.



### Main Features:

<b>IT(RMS)</b>	<b>VDRM/VRRM</b>	<b>VTM</b>
4 A	600V and 800 V	$\leq 1.8$ V

### Absolute Ratings(limiting values) :

<b>Symbol</b>	<b>Parameter</b>		<b>value</b>	<b>Unit</b>
<b>I<sub>T(RMS)</sub></b>	on-state RMS current(180°C conduction angle)		4	A
<b>I<sub>TSM</sub></b>	Non repetitive surge peak on-state current (T <sub>j</sub> = 25 °C)	tp= 8.3 ms	38	A
		tp = 10 ms	35	
<b>V<sub>DRM</sub></b>	Repetitive peak off-state voltage(T <sub>j</sub> =25 °C)		600 and 800	V
<b>V<sub>RMM</sub></b>	Repetitive peak reverse voltage(T <sub>j</sub> =25 °C)		600 and 800	V
<b>T<sub>stg</sub> T<sub>j</sub></b>	Storage and operating junction temperature range		- 40 to + 150 - 40 to + 125	°C
<b>I<sup>2</sup>t</b>	I <sup>2</sup> t value for fusing T <sub>j</sub> = 125°C	tp = 10 ms	6	A <sup>2</sup> s
<b>dI/dt</b>	Critical rate of rise of on-state current I <sub>G</sub> =2xI <sub>GT</sub> , tr≤100ns		50	A/μs

### Electrical Characteristics :

<b>Symbol</b>	<b>Test Condition</b>		<b>range</b>	<b>Value</b>	<b>Unit</b>
<b>I<sub>GT</sub></b>	V <sub>D</sub> =12V      R <sub>L</sub> =3.3kΩ	T <sub>j</sub> =25°C	MAX	20	mA
<b>V<sub>GT</sub></b>		T <sub>j</sub> =25°C	MAX	1.5	V
<b>V<sub>GD</sub></b>	V <sub>D</sub> =V <sub>DRM</sub> R <sub>L</sub> =3.3kΩ	T <sub>j</sub> =125°C	MIN	0.2	V
<b>t<sub>gt</sub></b>	V <sub>D</sub> =V <sub>DRM</sub> I <sub>G</sub> = 500mA    dI <sub>G</sub> /dt = 0.2A/μs	T <sub>j</sub> =25°C	TYP	2	μs
<b>I<sub>L</sub></b>	V <sub>D</sub> =12V    I <sub>GT</sub> = 0.1 A	T <sub>j</sub> =25°C	TYP	0.17	mA
<b>I<sub>H</sub></b>	I <sub>T</sub> = 500mA gate open	T <sub>j</sub> =25°C	MAX	6	mA
<b>V<sub>TM</sub></b>	I <sub>TM</sub> = 2*I <sub>T</sub> (RMS)    tp=380μs	T <sub>j</sub> =25°C	MAX	1.8	V
<b>I<sub>DRM</sub></b> <b>I<sub>RRM</sub></b>	V <sub>D</sub> =V <sub>DRM</sub> , V <sub>R</sub> =V <sub>RRM</sub>	T <sub>j</sub> =125°C	TYP	0.1	mA
		T <sub>j</sub> =125°C	MAX	0.5	mA
<b>dV<sub>D</sub>/dt</b>	V <sub>D</sub> =67%V <sub>DR</sub> — exponential waveform; R <sub>GR</sub> = 100 Ω	T <sub>j</sub> =125°C	TYP	50	V/μs

### Thermal Resistances :

<b>Symbol</b>	<b>Parameter</b>		<b>Value</b>	<b>Unit</b>
<b>R<sub>th (j-c)</sub></b>	junction to mounting case	TO-251/252	2.5	°C/W
<b>R<sub>th (j-a)</sub></b>	Junction to ambient	TO-251/252	60	K/W

Fig.1: Maximum average power dissipation versus average on-state current .

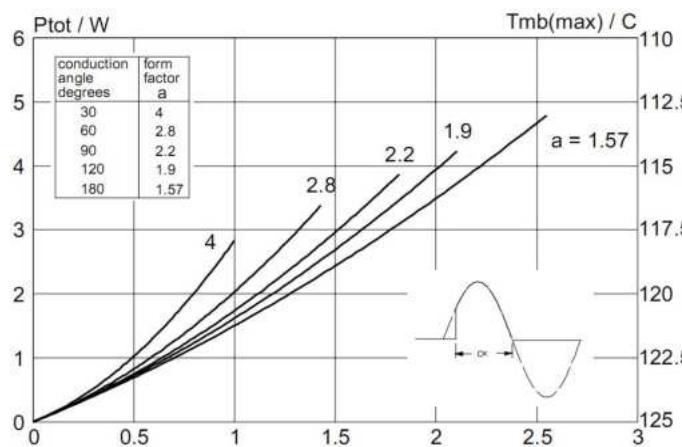


Fig.3 : Typical and maximum on-state characteristic.

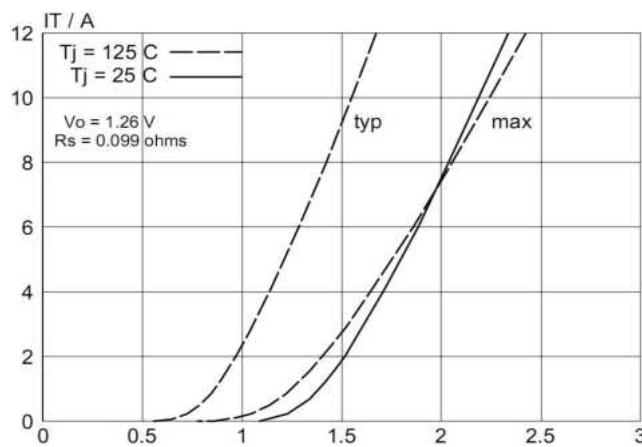


Fig.5 : Maximum permissible repetitive rms on-state current  $IT(RMS)$ , versus surge duration, for sinusoidal currents,  $f = 50$  Hz;  $Tmb \leqslant 113^\circ C$

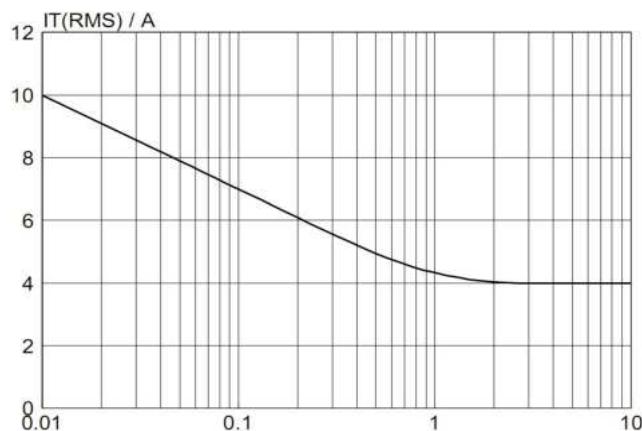


Fig.2 : Maximum permissible non-repetitive peak on-state current  $ITSM$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \leqslant 10ms$

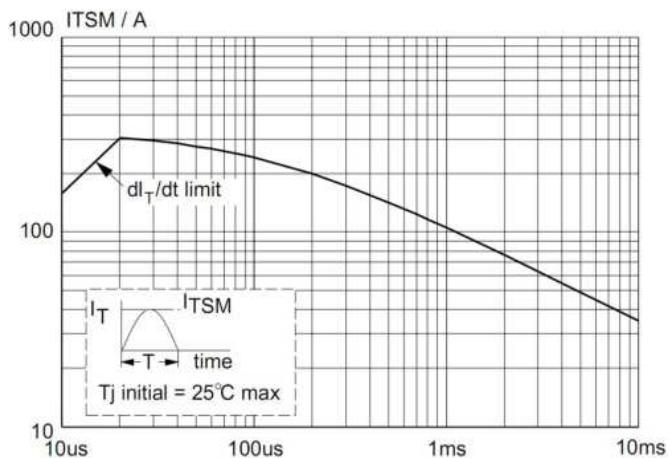


Fig.4 : Maximum permissible RMS current  $IT(RMS)$  , versus mounting base temperature  $Tmb$ .

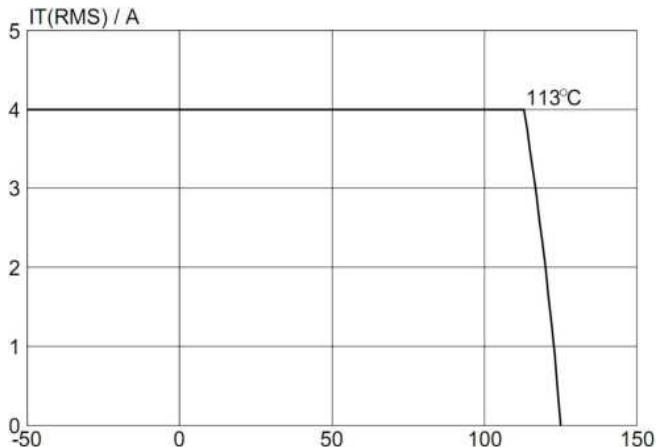


Fig.6: Normalised gate trigger voltage  $VGT(Tj)/ VGT(25^\circ C)$ , versus junction temperature  $Tj$

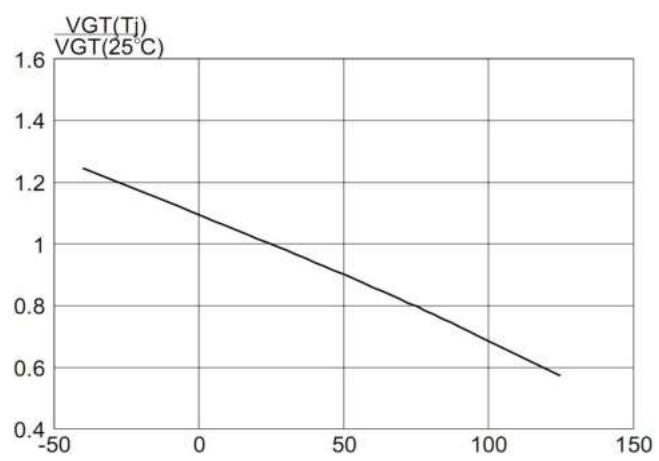


Fig.7 : Typical, critical rate of rise of off-state voltage,  $dV_D/dt$  versus junction temperature  $T_j$

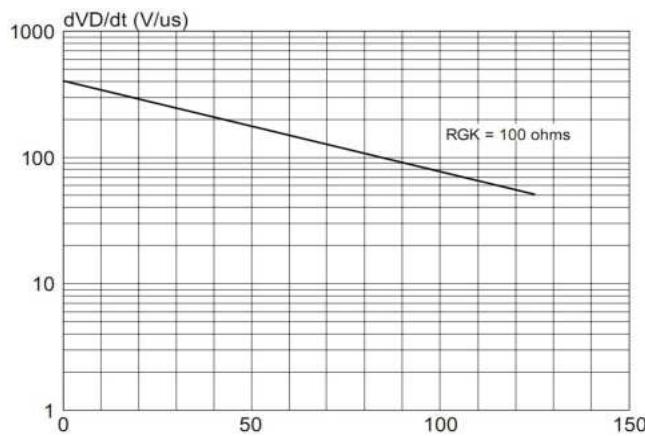
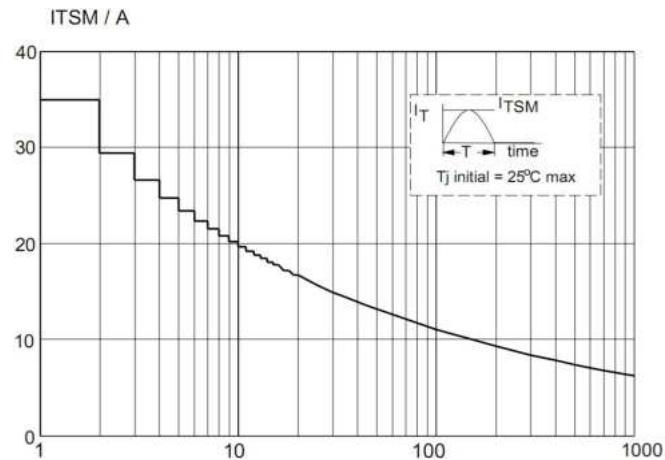
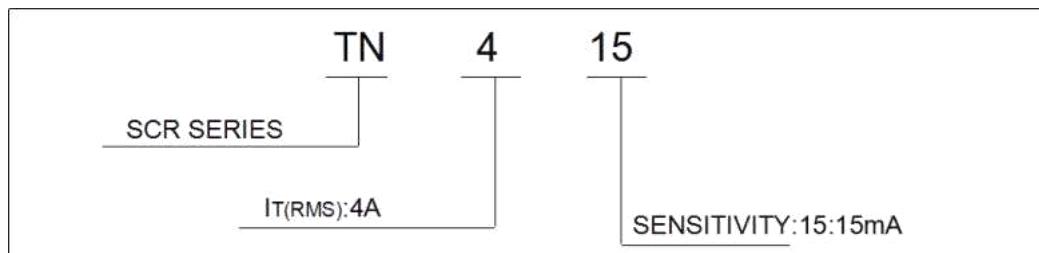


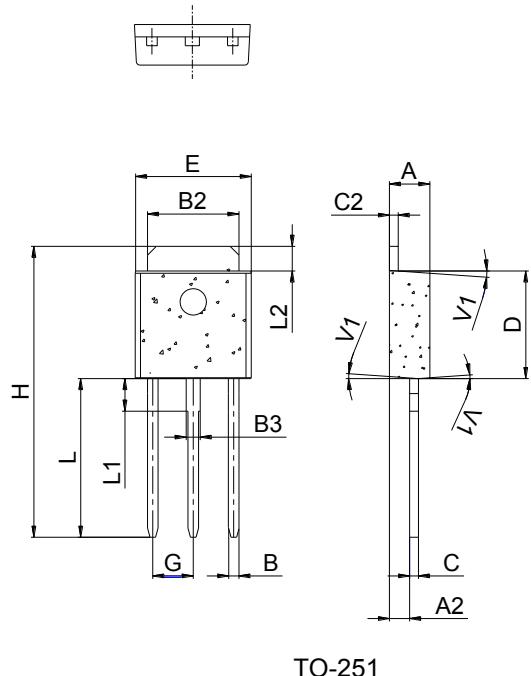
Fig.6: Non repetitive surge peak on-state current versus number of cycles.



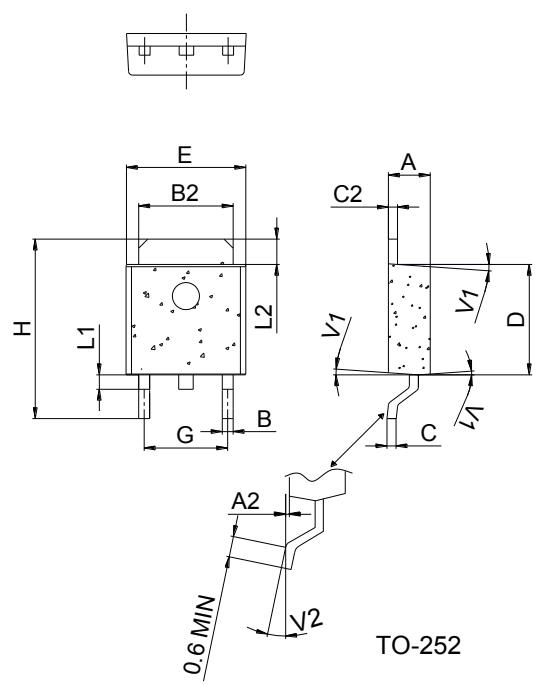
### Ordering Information



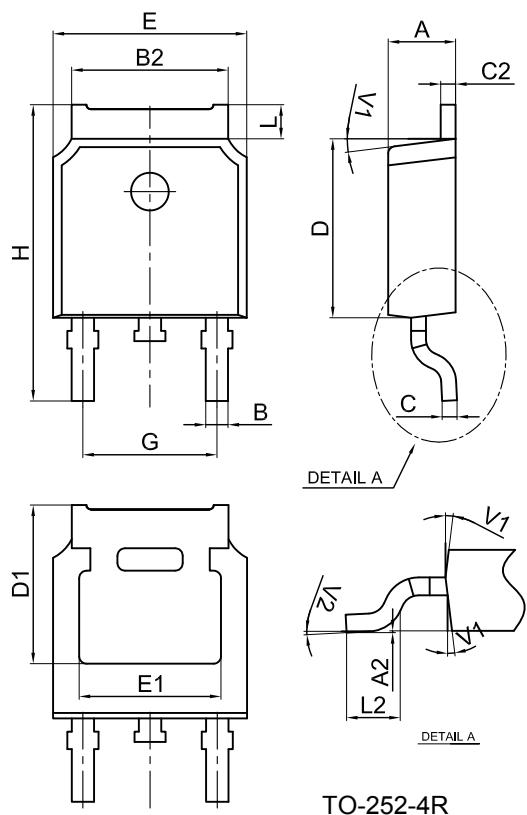
### Package Mechanical Data :



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.90		1.20	0.035		0.047
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
B3	0.76		0.85	0.030		0.033
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G		2.30			0.091	
H	16.0		17.0	0.630		0.669
L	8.90		9.40	0.350		0.370
L1	1.80		1.90	0.071		0.075
L2	1.37		1.50	0.054		0.059
V1		4°			4°	



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.03		0.23	0.001		0.009
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G	4.40		4.70	0.173		0.185
H	9.35		10.6	0.368		0.417
L1	1.30		1.70	0.051		0.067
L2	1.37		1.50	0.054		0.059
V1		4°			4°	
V2	0°		8°	0°		8°



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°